





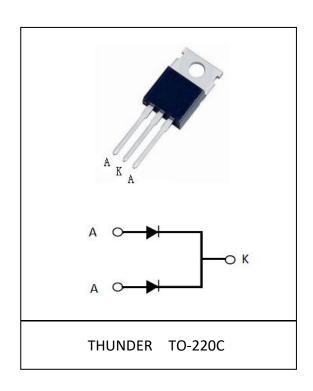
Thunder High Power Products

FRD Ultrafast Soft Recovery Diode, 16A

Features:

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I_R value
- High surge capacity
- Epitaxial chip construction

Product Summary			
VR	600 V		
lf(AV)	2*8A		
trr	21 ns		



Description/Applications

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

Absolute Maximum Ratings

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	Vrrm		600	V
Continuous forward current	lf(AV)	Tc =110°C	16	
Single pulse forward current	IFSM	Tc =25°C	160	А
Maximum repetitive forward current	IFRM	Square wave, 20kHZ	20	
Operating junction	Тј		175	°C
Storage temperatures	Tstg		-55 to +175	°C

Rev.A01 1/4





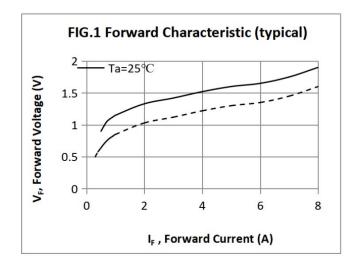
Electrical characteristics (Ta=25°C unless otherwise specified)

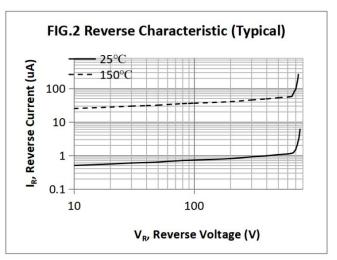
Parameter	Symbol	Test Conditions	Min	Тур.	Max.	Units
Breakdown voltage Blocking voltage	VBR, V _R	Ir=100µA	600			
Forward voltage (Per Diode)	IF=8A		1.35	1.70	V	
	VF	IF=8A, Tj =125°C		1.25	1.60	
Reverse leakage current(Per Diode)		VR= VRRM			20	
	Tj=150°C, Vr=600V			200	μ Α	
Reverse recovery time(Per Diode)	e recovery	I _F =0.5A, I _R =1A, I _{RR} =0.25A		32	50	
	trr	I _F =1A,V _R =30V, di/ <i>dt</i> =200A/us		21	35	ns

Thermal characteristics

Paramter	Symbol	Тур	Units
$R_{ heta JC}$	Junction-to-Case	2.0	°C/W

Electrical performance (typical per die)

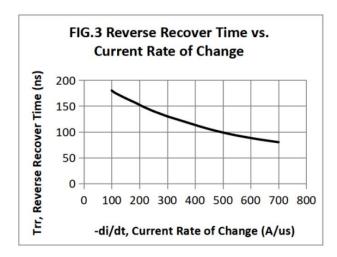


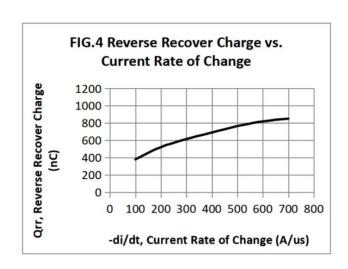


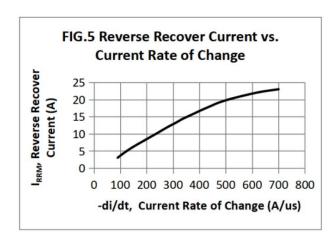
Rev.A01 2 / 4

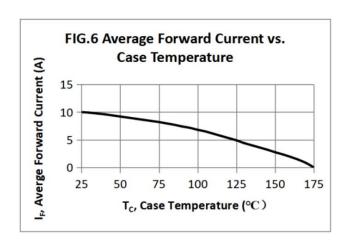


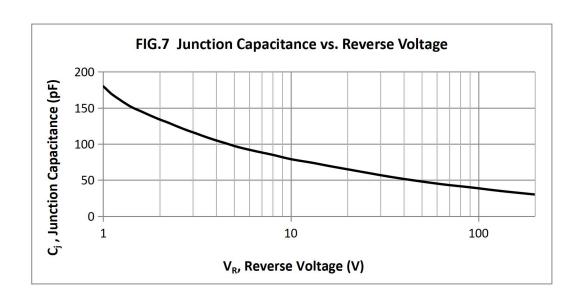












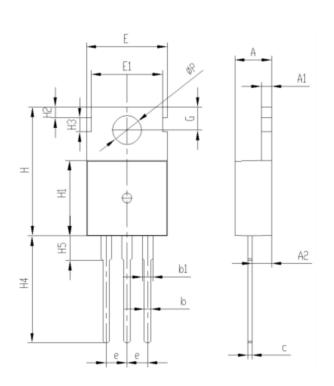
Rev.A01 3/4





Package Information

TO-220C PACKAGE



C: see le e l	Dimensions(millimeters)		
Symbol	Min.	Max.	
Α	4.30	4.70	
A1	1.17	1.37	
A2	2.20	2.60	
b	0.60	1.00	
b1	1.17	1.37	
b2	1.90	2.30	
С	0.30	0.70	
е	2.34	2.74	
E	9.70	10.1	
E1	8.50	8.90	
Н	15.5	15.9	
H1	9.00	9.40	
H2	1.10	1.50	
H3	1.50	1.90	
H4	12.58	13.58	
H5	2.80	3.20	
G	2.60	3.00	
ΦР	3.40	3.80	

Notice

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Rev.A01 4 / 4